



**AP7363** 

### 1.5A LOW QUIESCENT CURRENT, FAST TRANSIENT **ULTRA-LOW DROPOUT LINEAR REGULATOR**

## **Description**

The AP7363 is a 1.5A, adjustable output voltage, linear regulator with ultra-low dropout. The device includes pass element, error amplifier, band-gap, current limit, and thermal shutdown circuitry.

The device's characteristics of low dropout voltage and fast transient response to step changes in load make the device suitable for lowvoltage microprocessor applications. The typical quiescent current is approximately 0.5mA and changes little with load current. The built-in current-limit and thermal-shutdown functions prevent IC damage in fault conditions.

This device is available in the U-DFN2030-8, SO-8EP, SOT223, and TO252 packages.

### **Features**

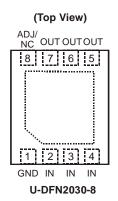
- 1.5A Ultra-Low Dropout Linear Regulator
- Ultra-Low Dropout: 190mV at 1.5A
- Stable With 10µF Input/Output Capacitor, Any Types
- Wide Input Voltage Range: 2.2V to 5.5V Adjustable Output Voltage: 0.6V to 5.0V
- Fixed Output Options: 1V, 1.2V, 1.5V, 1.8V, 2.5V, 3.3V
- Low Ground Pin Current
- 25nA Quiescent Current in Shutdown Mode
- Excellent Load/Line Transient Response
- Current Limit and Thermal Shutdown Protection
- Ambient Temperature Range: -40°C to +85°C
- U-DFN2030-8, SO-8EP, SOT223 and TO252: Available in "Green" Molding Compound (No Br, Sb)
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Diodes automotive grade parts (Q-suffix) are suitable for automotive applications requiring specific change control; these parts are AEC-Q100/101/200 qualified, PPAP capable, and manufactured in IATF16949:2016 certified facilities.

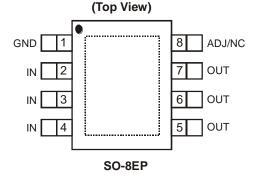
https://www.diodes.com/quality/product-definitions/

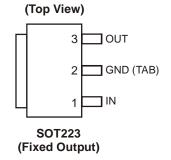
## **Applications**

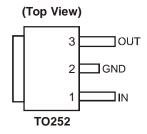
- ASIC Power Supplies In Printers, Graphics Cards, DVD Players, STBs, Routers, etc.
- FPGA and DSP Core or I/O Power Supplies
- **SMPS** Regulators
- Conversion From 3.3V or 5V Rail

## **Pin Assignments**









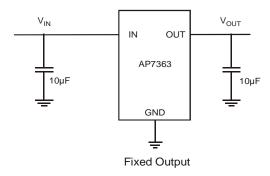
Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.

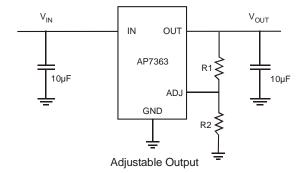
2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.



## **Typical Applications Circuit**



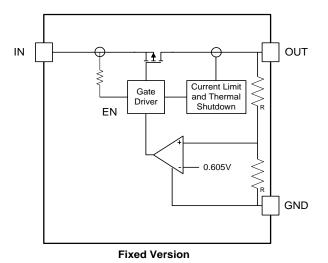


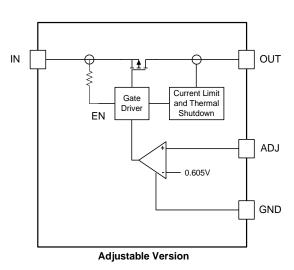
$$V_{OUT} = V_{REF} \left( 1 + \frac{R_1}{R_2} \right)$$
 where  $R_2 \le 10k\Omega$ 

## **Pin Descriptions**

Pin Number Pin Name SOT223 U-DFN2030-8 TO252 SO-8EP		umber		
			Function	
GND	2	1	Ground	
IN	1	2, 3, 4	Voltage Input Pin	
OUT	3	5, 6, 7	Voltage Output Pin	
ADJ	NA	Output feedback pin for adjustable version only—a resistor divider from this the OUT pin and ground sets the output voltage.		
NC	NA	8	No connection for fixed output version.	
EP/TAB	_	_	The exposed pad (EP) removes heat from the package, and it is recommended that the EP is connected to a copper area. The die is electrically connected to the exposed pad. It is recommended to connect the EP externally to GND, but it should not be the only ground connection.	

# **Functional Block Diagram**





AP7363 Document number: DS35059 Rev. 10 - 2 2 of 15

October 2021 © Diodes Incorporated



# Absolute Maximum Ratings (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Symbol	Parameter	Ratings	Unit
ESD HBM	Human Body Model ESD Protection	2000	V
ESD MM	Machine Model ESD Protection	200	V
V <sub>IN</sub>	Input Voltage	-0.3 to +6.0	V
Vout	OUT Voltage	-0.3 to V <sub>IN</sub> +0.3	V
Гоит	Continuous Load Current	Internal Limited	_
T <sub>ST</sub>	Storage Temperature Range	-65 to +150	°C
TJ	Maximum Junction Temperature	150	°C

## Recommended Operating Conditions (@ T<sub>A</sub> = +25°C, unless otherwise specified.)

Symbol	Parameter	Min	Max	Unit
$V_{IN}$	Input Voltage	2.2	5.5	V
I <sub>OUT</sub>	Output Current	0	1.5	А
T <sub>A</sub>	Operating Ambient Temperature	-40	+85	°C
TJ	Operating Junction Temperature (Note 5)	-40	+125	°C

Notes:

<sup>4.</sup> Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated are not implied. Exposure to absolute-maximum rated conditions for extended periods may affect device reliability.

conditions for extended periods may affect device reliability.

5. Operating junction temperature must be evaluated and derated as needed, based on ambient temperature (T<sub>A</sub>), power dissipation (P<sub>D</sub>), maximum allowable operating junction temperature (T<sub>J-MAX</sub>), and package thermal resistance (θ<sub>JA</sub>).



# $\textbf{Electrical Characteristics} \ ( \textcircled{@} \ T_{A} = +25 ^{\circ}\text{C}, \ V_{IN} = 3.3 \text{V}, \ I_{OUT} = 1 \\ \underline{0} \text{mA}, \ C_{IN} = 10 \\ \mu\text{F}, \ C_{OUT} = 10 \\ \mu\text{F}, \ unless otherwise specified.} )$

Minimum and maximum limits are guaranteed through test, design, or statistical correlation. Typical values represent the most likely parametric norm at  $T_A = +25$ °C, and are provided for reference purposes only.

Symbol	Parameter	Test Condition	าร	Min	Тур	Max	Unit
	AD I Din Voltono	$V_{IN} = V_{IN-MIN}$ to $V_{IN-MAX}$ ,	T <sub>A</sub> = +25°C	0.584	0.605	0.626	V
$V_{ADJ}$	ADJ Pin Voltage	$I_{OUT} = 10$ mA to 1.5A	Over temp	0.575	_	0.635	V
	AD I Die Dies Coment	\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\	T <sub>A</sub> = +25°C	_	50	_	- nA
I <sub>ADJ</sub>	ADJ Pin Bias Current	$V_{IN} = V_{IN-MIN}$ to $V_{IN-MAX}$	Over temp	_	_	750	
	Dranguit Valtage (Note 6)	1 450 1/ 051/	T <sub>A</sub> = +25°C	_	190	240	\/
V <sub>DROPOUT</sub>	Dropout Voltage (Note 6)	$I_{OUT} = 1.5A, V_{OUT} = 2.5V$	Over temp	_	_	280	mV
427 / 427	Line Demulation (Note 7)	V V +- V	T <sub>A</sub> = +25°C	_	0.04	_	%/V
$\Delta V_{OUT} / \Delta V_{IN}$	Line Regulation (Note 7)	VIN = VIN-MIN to VIN-MAX	Over temp	_	0.05		%/V
437 / 41	Load Regulation (Note 7)	1 40 1 +- 1 51	T <sub>A</sub> = +25°C	_	0.18	_	%/A
ΔVOUT / ΔΙΟυΤ	Load Regulation (Note 7)	$I_{OUT} = 10$ mA to 1.5A	Over temp	_	0.33		- %/A
	Ground Pin Current in Normal	1 40 1 +- 1 51	T <sub>A</sub> = +25°C	_	1.0	1.2	mA
	Operation Mode	$I_{OUT} = 10$ mA to 1.5A	Over temp	_	_	1.3	
I <sub>OUT-PK</sub>	Peak Output Current	V <sub>OUT</sub> ≥ V <sub>OUT</sub> - NOM -5%			_	_	Α
	Short Circuit Current	IOUT Grounded	T <sub>A</sub> = +25°C	_	3.7	_	A
Isc			Over temp	2	_	_	
t <sub>d(off)</sub>	Turn-Off Delay	From V <sub>EN</sub> < V <sub>IL</sub> to V <sub>OUT</sub> = OFF	, I <sub>OUT</sub> = 1.5A	_	25	_	μs
t <sub>d(on)</sub>	Turn-On Delay	From V <sub>EN</sub> > V <sub>IH</sub> to V <sub>OUT</sub> = ON, I <sub>OUT</sub> = 1.5A		_	25	_	μs
	Ripple Rejection	V <sub>IN</sub> = 3.0V, I <sub>OUT</sub> = 1.5A, f = 120Hz		_	65	_	
PSRR		V <sub>IN</sub> = 3.0V, I <sub>OUT</sub> = 1.5A, f = 1kHz		_	61	_	dB
Pn(l/f)	Output Noise Density	F = 120Hz, C <sub>OUT</sub> = 10µF Cera		_	1.0	_	μV/√Hz
Į- II(s)	,	BW = 100Hz - 100kHz,	· · · · · · · · · · · · · · · · · · ·	_	_	_	
e <sub>n</sub>	Output Noise Voltage	C <sub>OUT</sub> = 10µF Ceramic		100	100		μV(rms)
T <sub>SHDN</sub>	Thermal Shutdown Threshold	T <sub>J</sub> Rising		_	170	_	
T <sub>HYS</sub>	Thermal Shutdown Hysteresis	T <sub>J</sub> Falling From T <sub>SHDN</sub>		_	10	_	°C
		U-DFN2030-8 (Note 8)		_	85.0	_	
	Thermal Resistance Junction-to-	SO-8EP (Note 8)		_	52.8	_	1 .OAA/
ӨЈА	Ambient	SOT223 (Note 8)		_	105.7	_	°C/W
		TO252 (Note 8)		_	87.8	_	
		U-DFN2030-8 (Note 8)		_	17.0	_	°C/W
θ <sub>JC</sub>	Thermal Resistance Junction-to-Case	SO-8EP (Note 8)		_	10.0	_	
O JC	The man resistance sandion to sase	SOT223 (Note 8)		_	18.5	_	
		TO252 (Note 8)	_	17.3	_		

Notes:

4 of 15 AP7363 October 2021 © Diodes Incorporated Document number: DS35059 Rev. 10 - 2

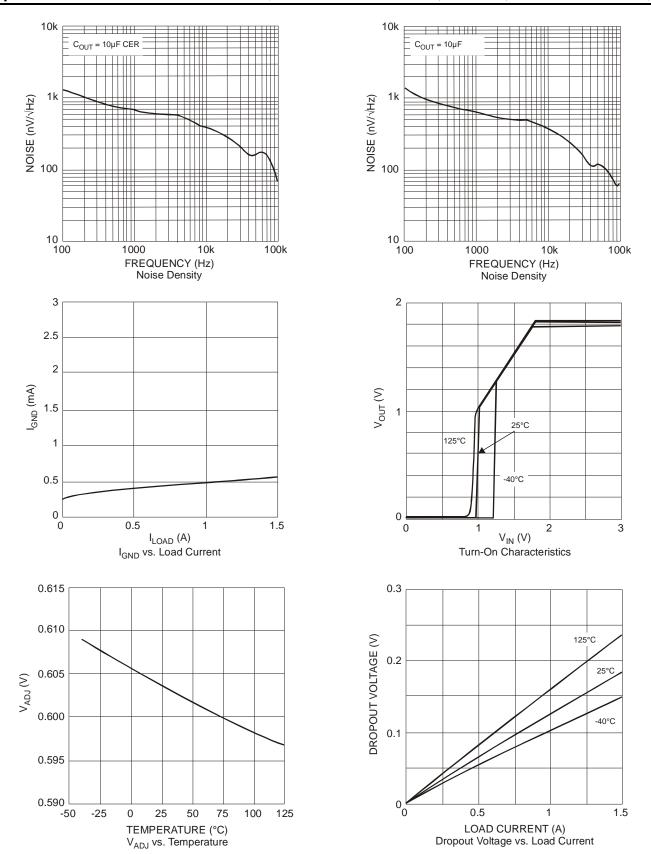
<sup>6.</sup> Dropout voltage is the minimum voltage difference between the input and the output at which the output voltage drops 2% below its nominal value. For any output voltage less than 2.5V, the minimum  $V_{\text{IN}}$  operating voltage is the limiting factor.

<sup>7.</sup> The line and load regulation specification contains only the typical number. However, the limits for line and load regulation are included in the adjust voltage tolerance specification.

<sup>8.</sup> Device mounted on 2" x 2" FR-4 substrate PCB, 2oz copper with minimum recommended pad layout.



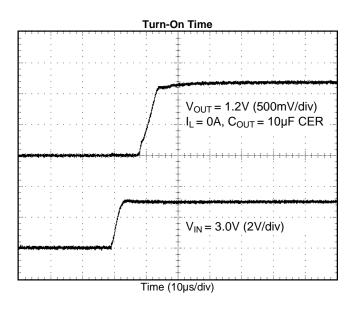
## $\textbf{Typical Performance Characteristics} \ (@\ T_J = +25^{\circ}\text{C},\ V_{\text{IN}} = 2.7\text{V},\ C_{\text{IN}} = 10\mu\text{F},\ C_{\text{OUT}} = 10\mu\text{F},\ I_{\text{OUT}} = 10\text{mA},\ V_{\text{OUT}} = 1.8\text{V})$

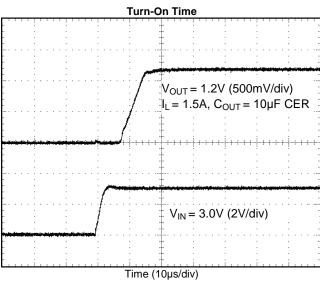


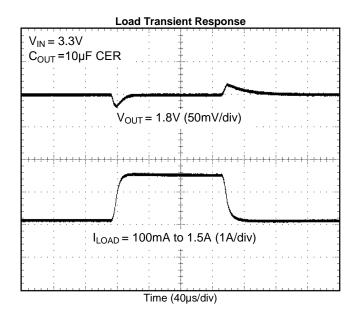


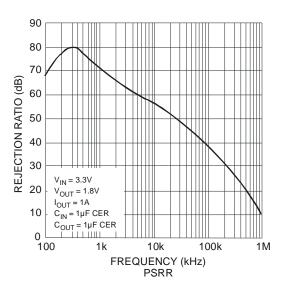
## **Typical Performance Characteristics** (continued)

(@  $T_J = +25$ °C,  $V_{IN} = 2.7$ V,  $C_{IN} = 10\mu$ F,  $C_{OUT} = 10\mu$ F,  $I_{OUT} = 10$ mA,  $V_{OUT} = 1.8$ V)











## **Application Note**

#### **Input Capacitor**

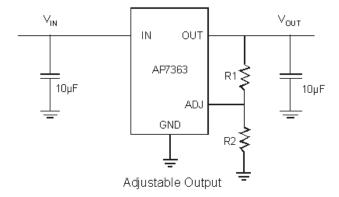
A minimum 2.2µF ceramic capacitor is recommended between IN and GND pins to decouple input power supply glitch and noise. The amount of the capacitance can be increased without limit. A larger input capacitor, like 10µF, provides better load transient response. This input capacitor must be located as close as possible to the device to assure input stability and to reduce noise. For PCB layout, a wide copper trace is required for both IN and GND pins. A lower ESR capacitor type allows the use of less capacitance, while a higher ESR type requires more capacitance.

#### **Output Capacitor**

The output capacitor is required to stabilize and help the transient response of the LDO. The AP7363 is stable with any type of capacitor with no limitations on minimum or maximum ESR. The device is designed to have excellent transient response for most applications with a small amount of output capacitance. The device is also stable with multiple capacitors in parallel, which can be of any type of value. Additional capacitance helps reduce undershoot and overshoot during transient loads. This capacitor must be placed as close as possible to OUT and GND pins for optimum performance.

#### **Adjustable Operation**

The AP7363 provides output voltage from 0.6V to 5.0V through external resistor divider as shown below.



The output voltage is calculated by the following equation:

$$V_{OUT} = V_{REF} \left( 1 + \frac{R_1}{R_2} \right)$$

Where  $V_{REF} = 0.6V$  (the internal reference voltage)

Rearranging the previous equation gives the following equation that is used for adjusting the output to a particular voltage:

$$R_1 = R_2 \left( \frac{V_{OUT}}{V_{RFF}} - 1 \right)$$

To maintain the stability of the internal reference voltage,  $R_2\,\text{must}$  be kept smaller than  $10k\Omega$ 

#### No Load Stability

Other than external resistor divider, no minimum load is required to keep the device stable. The device will remain stable and regulated in no load condition.

AP7363 7 of 15

Document number: DS35059 Rev. 10 - 2 Downloaded From Oneyac.com

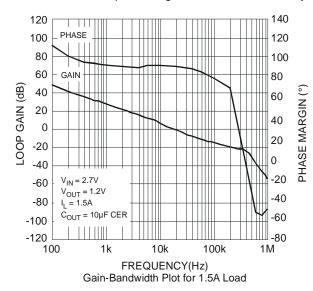


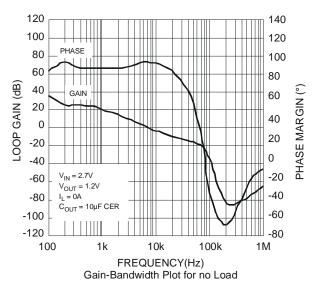
## **Application Note** (continued)

#### Stability and Phase Margin

Any regulator that operates using a feedback loop must be compensated in such a way as to ensure adequate phase margin, which is defined as the difference between the phase shift and -180 degrees at the frequency where the loop gain crosses unity (0 dB). For most LDO regulators, the ESR of the output capacitor is required to create a zero to add enough phase lead to ensure stable operation. The AP7363 has an internal compensation circuit that maintains phase margin regardless of the ESR of the output capacitor—any type of capacitors can be used.

The following charts show the gain/phase plot of the AP7363 with an output of 1.2V, 10µF ceramic output capacitor, and delivering 1.5A load current and no load. The phase margin is about 90°, which is very stable.





#### **Short-Circuit Protection**

When the output current at the OUT pin is higher than the current limit threshold, the current limit protection triggers and clamps the output current to prevent overcurrent and to protect the regulator from damage due to overheating.

#### **Thermal Shutdown Protection**

Thermal protection disables the output when the junction temperature rises to approximately +170°C, which allows the device to cool down. When the junction temperature reduces to approximately +160°C, the output circuitry is enabled again. Depending on power dissipation, thermal resistance, and ambient temperature, the thermal protection circuit may cycle on and off. This cycling limits the heat dissipation of the regulator and protects it from damage due to overheating.

#### Low Quiescent Current

The AP7363, consuming only around 0.5mA for all input range, provides great power saving in portable and low-power applications.

#### **Output Noise**

This is the integrated value of the output noise over a specified frequency range. Input voltage and output load current are kept constant during the measurement. Results are expressed in  $\mu Vrms$  or  $\mu V\sqrt{Hz}$ .

The AP7363 is a low-noise regulator and requires no external noise reduction capacitor. Output voltage noise is typically 100µVrms, and overall noise level is between 100 Hz and 100 kHz.

Noise is specified in two ways:

Output noise density is the RMS sum of all noise sources, measured at the regulator output, at a specific frequency (measured with a 1Hz bandwidth). This type of noise is usually plotted on a curve as a function of frequency.

Output noise voltage is the RMS sum of spot noise over a specified bandwidth. Spot noise is measured in units  $\mu V/\sqrt{Hz}$  or  $nV/\sqrt{Hz}$ , and total output noise is measured in  $\mu V(rms)$ . The primary source of noise in low-dropout regulators is the internal reference.



## **Application Note** (continued)

#### **Power Dissipation**

The device power dissipation and proper sizing of the thermal plane connected to the thermal pad is critical to avoid thermal shutdown and ensure reliable operation. Power dissipation of the device depends on input voltage and load conditions and can be calculated by:

$$P_D = (V_{IN} - V_{OUT}) \times I_{OUT}$$

The maximum power dissipation, handled by the device, depends on the junction-to-ambient thermal resistance and maximum ambient temperature, which can be calculated by the following equation:

$$P_{D_max} = \frac{(+150^{\circ}C - T_A)}{R_{\theta JA}}$$

## **Ordering Information**

Output Package Packing

BLANK: ADJ HA: U-DFN203 7/13: Tape & Reel

 10:1.0V
 SP:SO-8EP

 12:1.2V
 E:SOT223-3L

 15:1.5V
 D:TO252-3L

18 : 1.8V 25 : 2.5V 33 : 3.3V

	Part Number	Backage Code	Packaging	7"/13" Tape and Reel		
	Fait Nullibei	Package Code (Note 9)		Quantity	Part Number Suffix	
Green	AP7363-XXHA-7	HA	U-DFN2030-8	3000/Tape & Reel	-7	
Green	AP7363-XXSP-13	SP	SO-8EP	2500/Tape & Reel	-13	
o Green	AP7363-XXE-13	Е	SOT223-3L	2500/Tape & Reel	-13	
3	AP7363-XXD-13	D	TO252-3L	2500/Tape & Reel	-13	

Note: 9. TO252 and SOT223 are only available with fixed output version.

AP7363

Document number: DS35059 Rev. 10 - 2

9 of 15

Downloaded From Oneyac.com



## **Marking Information**

### (1) U-DFN2030-8

### (Top View)

<u>XX</u>   $\underline{XX}$ : Identification Code  $\underline{Y}$ : Year: 0~9

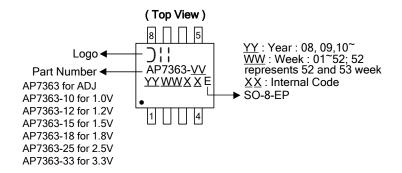
W : Week : A~Z : 1~26 week; a~z : 27~52 week; z represents

52 and 53 week

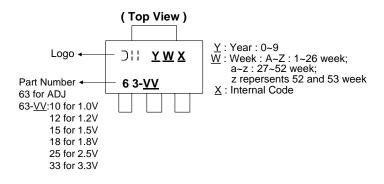
X: Internal Code

Device	Package	Identification Code
AP7363ADJ	U-DFN2030-8	SA
AP7363-10	U-DFN2030-8	SB
AP7363-12	U-DFN2030-8	SC
AP7363-15	U-DFN2030-8	SD
AP7363-18	U-DFN2030-8	SE
AP7363-25	U-DFN2030-8	SF
AP7363-33	U-DFN2030-8	SG

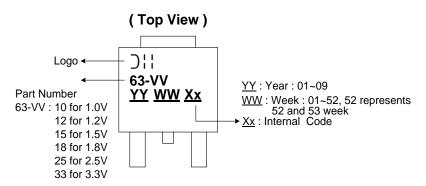
#### (2) SO-8EP



#### (3) SOT223



### (4) TO252

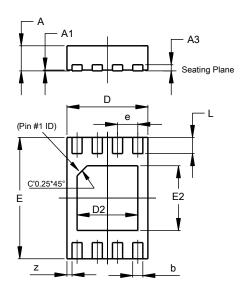




## Package Outline Dimensions (All dimensions in mm.)

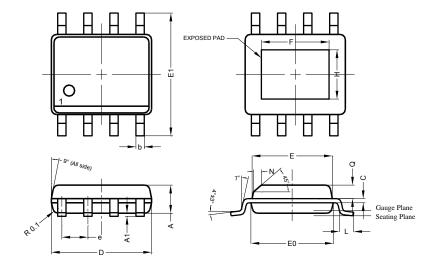
Please see http://www.diodes.com/package-outlines.html for the latest version.

### 1) U-DFN2030-8



	U-DFN2030-8					
Dim	Min	Max	Тур			
Α	0.57	0.63	0.60			
<b>A</b> 1	0	0.05	0.02			
A3	1	ı	0.15			
b	0.20	0.30	0.25			
D	1.95	2.05	2.00			
D2	1.40	1.60	1.50			
е	ı	ı	0.50			
Е	2.95	3.05	3.00			
E2	1.50	1.70	1.60			
L	0.35	0.45	0.40			
Ζ	-	-	0.125			
All	All Dimensions in mm					

### 2) SO-8EP



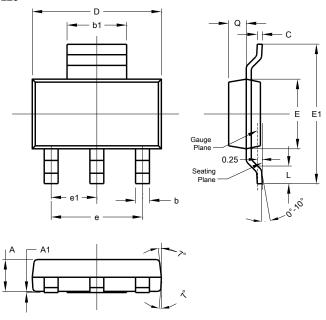
SO-8EP					
Dim	Min	Max	Тур		
Α	1.40	1.50	1.45		
A1	0.00	0.13	-		
b	0.30	0.50	0.40		
С	0.15	0.25	0.20		
D	4.85	4.95	4.90		
Е	3.80	3.90	3.85		
E0	3.85	3.95	3.90		
E1	5.90	6.10	6.00		
е	-	-	1.27		
F	2.75	3.35	3.05		
Н	2.11	2.71	2.41		
L	0.62	0.82	0.72		
N	-	-	0.35		
Q	0.60	0.70	0.65		
All Di	All Dimensions in mm				



## Package Outline Dimensions (continued) (All dimensions in mm.)

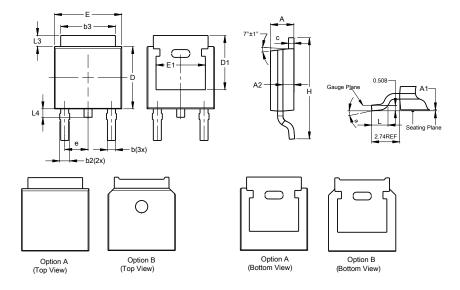
Please see http://www.diodes.com/package-outlines.html for the latest version.

### 3) SOT223



SOT223					
Dim	Min	Max	Тур		
Α	1.55	1.65	1.60		
A1	0.010	0.15	0.05		
b	0.60	0.80	0.70		
b1	2.90	3.10	3.00		
С	0.20	0.30	0.25		
D	6.45	6.55	6.50		
Е	3.45	3.55	3.50		
E1	6.90	7.10	7.00		
е	-	-	4.60		
e1	-	-	2.30		
L	0.85	1.05	0.95		
Q	0.84	0.94	0.89		
All [	Dimens	ions in	mm		

## 4) TO252 (Standard)



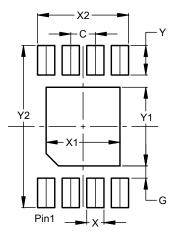
TO252 (Standard)					
Dim	Min	Max	Тур		
Α	2.19	2.39	2.29		
A1	0.00	0.13	0.08		
A2	0.97	1.17	1.07		
b	0.64	0.88	0.783		
b2	0.76	1.14	0.95		
b3	5.21	5.46	5.33		
С	0.45	0.58	0.531		
D	6.00	6.20	6.10		
D1	5.21	-	-		
е	-	-	2.286		
П	6.45	6.70	6.58		
E1	4.32	-	-		
H	9.40	10.41	9.91		
٦	1.40	1.78	1.59		
L3	0.88	1.27	1.08		
L4	0.60	1.02	0.83		
а	0°	10°	-		
All Dimensions in mm					



## **Suggested Pad Layout**

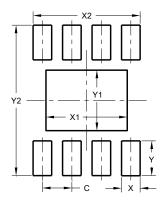
Please see http://www.diodes.com/package-outlines.html for the latest version.

### 1) U-DFN2030-8



Dimensions	Value (in mm)
С	0.500
G	0.250
Х	0.350
X1	1.500
X2	1.850
Y	0.600
Y1	1.600
Y2	3.300

### 2) SO-8EP



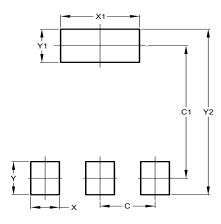
Dimensions	Value
ninensions	(in mm)
С	1.270
Х	0.802
X1	3.502
X2	4.612
Y	1.505
Y1	2.613
Y2	6.500



## Suggested Pad Layout (continued)

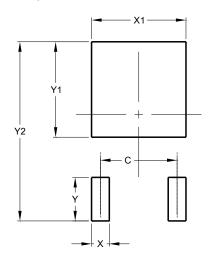
Please see http://www.diodes.com/package-outlines.html for the latest version.

### 3) SOT223



Dimensions	Value (in mm)
С	2.30
C1	6.40
Х	1.20
X1	3.30
Υ	1.60
Y1	1.60
Y2	8.00

### 4) TO252 (Standard)



Dimensions	Value (in mm)
С	4.572
Х	1.060
X1	5.632
Υ	2.600
Y1	5.700
Y2	10.700

## **Mechanical Data**

- Moisture Sensitivity: Level 1 Per J-STD-020
- Terminals:
  - SOT223/ SO-8EP/ TO252 : Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 <sup>©</sup>3
  - U-DFN2030-8: Finish NiPdAu over Copper Leads, Solderable per MIL-STD-202, Method 208 (4)
- Weight:
  - U-DFN2030-8: 0.0105 grams (Approximate)
  - SOT223: 0.113 grams (Approximate)
  - SO-8EP: 0.081 grams (Approximate)
  - TO252: 0.315 grams (Approximate)

AP7363 14 of 15 October 2021

Document number: DS35059 Rev. 10 - 2 Downloaded From Oneyac.com Oneyac.com



#### **IMPORTANT NOTICE**

- DIODES INCORPORATED AND ITS SUBSIDIARIES ("DIODES") MAKE NO WARRANTY OF ANY KIND, EXPRESS OR IMPLIED, WITH REGARDS TO ANY INFORMATION CONTAINED IN THIS DOCUMENT, INCLUDING, BUT NOT LIMITED TO, THE IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE OR NON-INFRINGEMENT OF THIRD PARTY INTELLECTUAL PROPERTY RIGHTS (AND THEIR EQUIVALENTS UNDER THE LAWS OF ANY JURISDICTION).
- The Information contained herein is for informational purpose only and is provided only to illustrate the operation of Diodes products described herein and application examples. Diodes does not assume any liability arising out of the application or use of this document or any product described herein. This document is intended for skilled and technically trained engineering customers and users who design with Diodes products. Diodes products may be used to facilitate safety-related applications; however, in all instances customers and users are responsible for (a) selecting the appropriate Diodes products for their applications, (b) evaluating the suitability of the Diodes products for their intended applications, (c) ensuring their applications, which incorporate Diodes products, comply the applicable legal and regulatory requirements as well as safety and functional-safety related standards, and (d) ensuring they design with appropriate safeguards (including testing, validation, guality control techniques, redundancy, malfunction prevention, and appropriate treatment for aging degradation) to minimize the risks associated with
- Diodes assumes no liability for any application-related information, support, assistance or feedback that may be provided by Diodes from time to time. Any customer or user of this document or products described herein will assume all risks and liabilities associated with such use, and will hold Diodes and all companies whose products are represented herein or on Diodes' websites, harmless against all damages and
- Products described herein may be covered by one or more United States, international or foreign patents and pending patent applications. Product names and markings noted herein may also be covered by one or more United States, international or foreign trademarks and trademark applications. Diodes does not convey any license under any of its intellectual property rights or the rights of any third parties (including third parties whose products and services may be described in this document or on Diodes' website) under this document.
- Diodes products are provided subject to Diodes' Standard Terms (https://www.diodes.com/about/company/terms-and-conditions/terms-and-conditions-of-sales/) or other applicable terms. This document does not alter or expand the applicable warranties provided by Diodes. Diodes does not warrant or accept any liability whatsoever in respect of any products purchased through unauthorized sales channel.
- Diodes products and technology may not be used for or incorporated into any products or systems whose manufacture, use or sale is prohibited under any applicable laws and regulations. Should customers or users use Diodes products in contravention of any applicable laws or regulations, or for any unintended or unauthorized application, customers and users will (a) be solely responsible for any damages, losses or penalties arising in connection therewith or as a result thereof, and (b) indemnify and hold Diodes and its representatives and agents harmless against any and all claims, damages, expenses, and attorney fees arising out of, directly or indirectly, any claim relating to any noncompliance with the applicable laws and regulations, as well as any unintended or unauthorized application.
- While efforts have been made to ensure the information contained in this document is accurate, complete and current, it may contain technical inaccuracies, omissions and typographical errors. Diodes does not warrant that information contained in this document is error-free and Diodes is under no obligation to update or otherwise correct this information. Notwithstanding the foregoing, Diodes reserves the right to make modifications, enhancements, improvements, corrections or other changes without further notice to this document and any product described herein. This document is written in English but may be translated into multiple languages for reference. Only the English version of this document is the final and determinative format released by Diodes.
- Any unauthorized copying, modification, distribution, transmission, display or other use of this document (or any portion hereof) is prohibited. Diodes assumes no responsibility for any losses incurred by the customers or users or any third parties arising from any such unauthorized use.

Copyright © 2021 Diodes Incorporated

www.diodes.com

15 of 15 AP7363 October 2021 © Diodes Incorporated Document number: DS35059 Rev. 10 - 2

# 单击下面可查看定价,库存,交付和生命周期等信息

>>Diodes Incorporated(达迩科技(美台))